

View Online at <https://aerobasegroup.com/nsn/5961-01-581-2519>

**Inclosure Material:**

Glass

**End Application:**

Ca70608-00 (19156) , receiver-transmitter

**Mounting Facility Quantity:**

2

**Mounting Method:**

Unthreaded hole

**Semiconductor Material:**

Silicon

**Voltage Rating In Volts Per Characteristic:**

60.0 collector to emitter voltage, dc and 4.0 emitter to base voltage, dc

**Current Rating Per Characteristic:**

1.00 amperes collector current, dc

**Power Rating Per Characteristic:**

50.0 watts forward power dissipation, dc and 7.0 watts power output

**Product Name:**

Dwg: rf transistor; cage: 7 watts, 50 volts, pulsed avionics 960 - 1215 mhz, common base bipolar transistor

**Precious Material And Location:**

Thin film metallization gold

**Shelf Life:**

N/a

**Unit Of Measure:**

--

**Demilitarization:**

No

**Fiig:**

A110a0